2N3704



2N3704



NPN General Purpose Amplifier

This device is designed for use as general purpose amplifiers and switches requiring collector currents to 300 mA. Sourced from Process 10. See PN100 for characteristics.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage	30	V
V _{CBO}	Collector-Base Voltage	50	V
V _{EBO}	Emitter-Base Voltage	5.0	V
Ic	Collector Current - Continuous	500	mA
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES: 1) These ratings are based on a maximum junction temperature of 150 degrees C. 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics

TA = 25°C unless otherwise noted		

Symbol	Characteristic	Max	Units
		2N3704	
P _D	Total Device Dissipation	625	mW
	Derate above 25°C	5.0	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	°C/W
$R_{\theta J A}$	Thermal Resistance, Junction to Ambient	200	°C/W

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NPN General Purpose Amplifier (continued)

Electrical Characteristics TA = 25°C unless otherwise noted					
Symbol	Parameter	Test Conditions	Min	Max	Units

OFF CHARACTERISTICS

V _{(BR)CEO}	Collector-Emitter Breakdown Voltage*	$I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 0$	30		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_{C} = 100 \ \mu A, \ I_{E} = 0$	50		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_{E} = 100 \ \mu A, \ I_{C} = 0$	5.0		V
I _{CBO}	Collector Cutoff Current	$V_{CB} = 20 \text{ V}, I_E = 0$		100	nA
I _{EBO}	Emitter Cutoff Current	$V_{EB} = 3.0 \text{ V}, I_{C} = 0$		100	nA

ON CHARACTERISTICS*

h _{FE}	DC Current Gain	$V_{CE} = 2.0 \text{ V}, I_{C} = 50 \text{ mA}$	100	300	
V _{BE(on)}	Base-Emitter ON Voltage	$V_{CE} = 2.0 \text{ V}, I_{C} = 100 \text{ mA}$	0.5	1.0	V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_{\rm C} = 100 \text{ mA}, I_{\rm B} = 5.0 \text{ mA}$		0.6	V

SMALL SIGNAL CHARACTERISTICS

C _{ob}	Output Capacitance	V _{CB} = 10 V, f = 1.0 MHz		12	pF
f _T	Current Gain - Bandwidth Product	$I_{C} = 50 \text{ mA}, V_{CE} = 2.0 \text{ V},$	100		MHz

*Pulse Test: Pulse Width \leq 300 $\mu s,$ Duty Cycle \leq 2.0%



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